



# HVRL200

## 20kV 30mA HIGH VOLTAGE DIODE

**HVRL** is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

### ■ Features

- High speed switching
- Low VF
- High surge resistivity for CRT discharge
- High reliability design
- Ultra small pakage

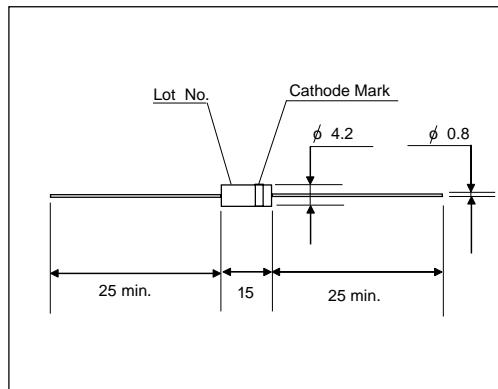
### ■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

### ■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

### ■ Outline Drawings : mm



### ■ Cathode Mark

Type	Mark
HVRL200	

Items	Symbols	Condition	HVRL200	Units
Repetitive Peak Renerse Voltage	$V_{RRM}$		20	kV
Average Output Current	$I_o$	$T_a=25^{\circ}\text{C}$ , Resistive Load	30	mA
Suege Current	$I_{FSM}$	10mS Sine-half wave peak value	5.0	$\text{A}_{\text{peak}}$
Junction Temperature	$T_j$		155	$^{\circ}\text{C}$
Allowable Operation Case Temperature	$T_c$		125	$^{\circ}\text{C}$
Storage Temperature	$T_{stg}$		-40 to +155	$^{\circ}\text{C}$

- Electrical Characteristics ( $T_a=25^{\circ}\text{C}$  Unless otherwise specified )

Items	Symbols	Conditions	HVRL200	Units
Maximum Forward Voltage Drop	$V_F$	at $25^{\circ}\text{C}$ , $I_F=I_{F(AV)}$	35	V
Maximum Reverse Current	$I_R1$	at $25^{\circ}\text{C}$ , $VR=20\text{kV}$	2.0	$\mu\text{A}$
	$I_R2$	at $100^{\circ}\text{C}$ , $VR=20\text{kV}$	20	$\mu\text{A}$
Maximum Reverse Recovery Time	$T_{rr}$	at $25^{\circ}\text{C}$ , $I_F=2\text{mA}$ , $I_R=4\text{mA}$	100	nS
Junction Capacitance	$C_j$	at $25^{\circ}\text{C}$ , $VR=0\text{V}$ , $f=1\text{MHz}$	1.0	pF